

4/16/04

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

**Title of
Invention****METHOD OF FABRICATING A CMOS DEVICE WITH DUAL
METAL GATE ELECTRODES**

Application Number : 10/826665
Confirmation Number: 9608
First Named Applicant: CHANG PARK
Attorney Docket Number: 61472-0308425
Art Unit:
Examiner:
Search string: (6653698 or 6352913).pn

**US Patent Documents****Note: Applicant is not required to submit a paper copy of cited US Patent Documents**

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
MDP	1	6653698	2003-11-25	LEE ET AL.	B2	257	407
MDP	2	6352913	2002-03-05	MISTRY ET AL.	B1	438	587

Signature

Examiner Name	Date
<i>Christopher D. Hansen</i>	3/17/06